

Model of the Si IV emission at the loop footpoints heated by an electron beam

Model

➤ goal is to model observed spectral characteristic of Si IV line during impulsive phase of solar flare

➤ radiative-hydrodynamic code FLARIX is used to obtain temporally dependent plasma parameters in the flaring loop – temperature, electron density, velocity, energy deposition...

➤ FLARIX allows us to model the time evolution of a 1D atmosphere heated by a specified process, e.g. by electron beams propagating from the injection site in the corona down to the lower atmosphere

➤ triangle time modulation of energy deposition function is used

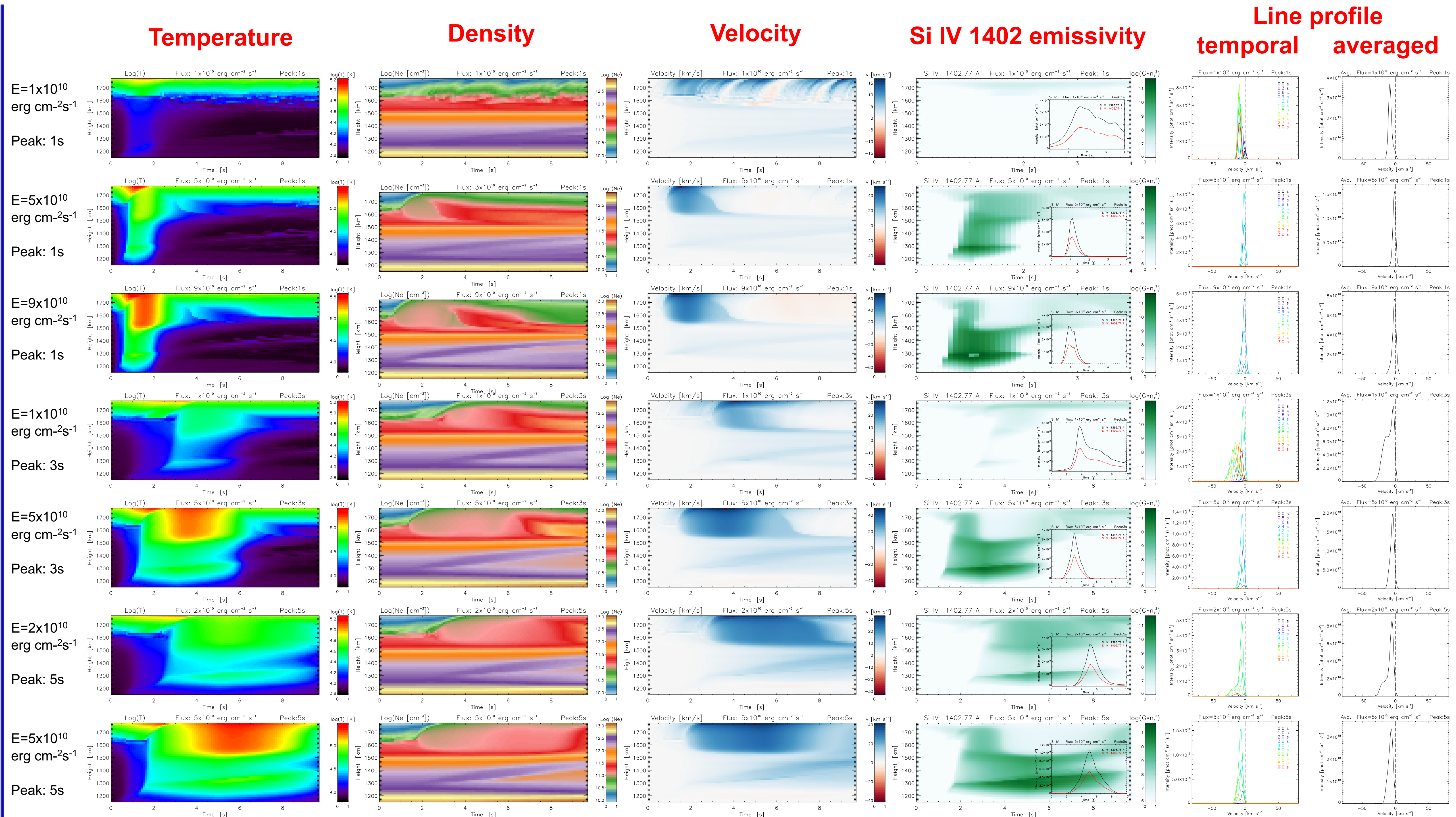
➤ electron beam parameters: maximum beam energy flux $E = 1-10 \times 10^{10} \text{ erg cm}^{-2} \text{ s}^{-1}$, power-law index of electron beam is -3, low energy cut-off is 20 keV, total deposition time is 2-10 s

➤ for selected beam parameters, time dependent ionization states and relative abundances of Si IV ion are calculated.

➤ contribution of the electron beam to the ionization and excitation rates is included

➤ Si IV emissivity (1402.77 Å) together with temporal and integrated line profiles are showed

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- Si IV is formed in two main regions – in the beginning chromosphere at the height about 1300 km and about 1500 km. Their locations correlate with temperature structure and $\text{Log}(T/K)$ about 4.8
- time dependence of total line intensity copies more or less time modulation of energy deposition function
- time behavior of line Doppler shift is similar to observations, however, its amplitude is much lower than observed values
- modeled plasma velocities (a few of tens of km/s) and widths of the modeled lines are too low
- wider range of input parameters for FLARIX code is needed to model observed velocities
- line width should be widened by micro-turbulence